

ROHS

HALOGEN FREE

Hyperfast Rectifier, 60 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS						
I _{F(AV)}	60 A					
V_{R}	1200 V					
V _F at I _F at 125 °C	1.7 V					
t _{rr}	38 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

FEATURES

- · Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature

Polyimide passivation

- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals**: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 111 °C, D = 0.50	60				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	425	Α			
Repetitive peak forward current	I _{FRM}	T _C = 111 °C, D = 0.50, f = 20 kHz	120				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 60 A	-	1.9	2.5	V		
		I _F = 60 A, T _J = 125 °C	-	1.7	-			
De construit de la construit d	I _R	$V_R = V_R$ rated	-	-	50	μА		
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500			
Junction capacitance	C _T	V _R = 200 V	-	32	-	рF		
Series inductance	L _S	Measured to lead 5 mm from package body	ı	8	-	nΗ		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		38	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	130	-	ns	
		T _J = 125 °C		-	200	-	1	
Peak recovery current		T _J = 25 °C	$I_F = 40 \text{ A}$	-	22	-	А	
	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/μs V _R = 400 V	-	39	-		
Deviana nacevani chema	Q _{rr}	T _J = 25 °C		-	1610	-	nC	
Reverse recovery charge		T _J = 125 °C		-	4080	-		
Deviana nagavan tima		T _J = 25 °C	I _F = 60 A dI _F /dt = 1000 A/μs · V _B = 800 V	-	100	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	153	-		
Dools recovery assured		T _J = 25 °C		-	40	-	A	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	67	-		
Reverse recovery charge		T _J = 25 °C		-	2590	-	nC	
	Q _{rr}	T _J = 125 °C		-	6150	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.4	°C/W		
Weight			-	5.5	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-247AD 2L	E5PH6012LH					

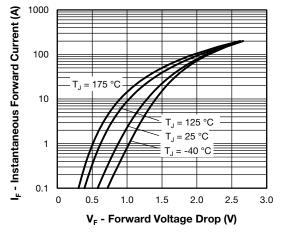


Fig. 1 - Typical Forward Voltage Drop Characteristics

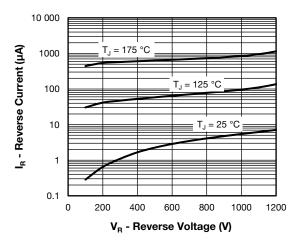


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



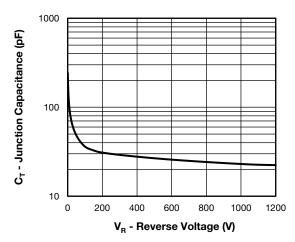


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

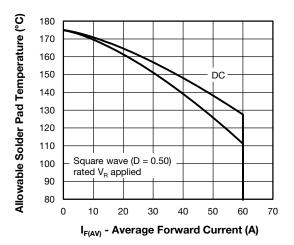


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

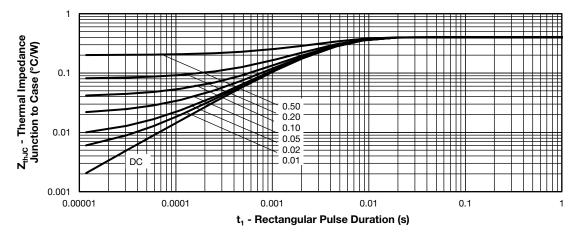


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

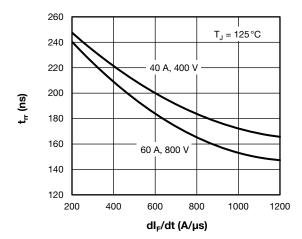


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

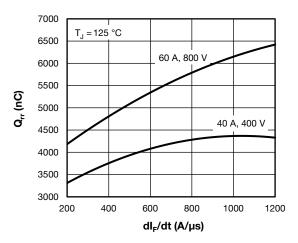


Fig. 7 - Typical Stored Charge vs. dl_F/dt

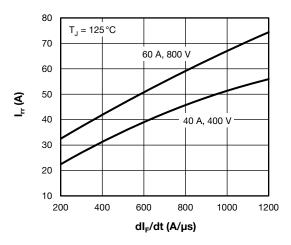


Fig. 8 - Typical Recovery Current vs. dl_F/dt

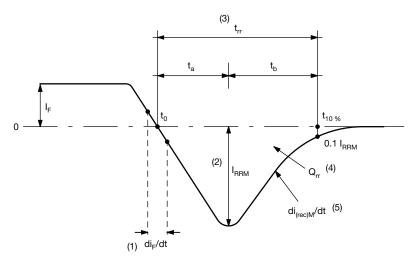


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RBM}
- $^{(4)}~$ Q_{rr} area under curve defined by t_0 and $t_{10}\,\%$

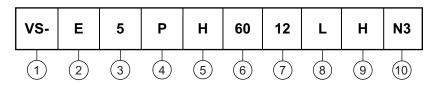
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode, 2 pins

3 - FRED Pt Gen 5

- P = TO-247 package

5 - Process type:

H = hyperfast recovery

6 - Current rating (60 = 60 A)

7 - Voltage rating (12 = 1200 V)

8 - L = long lead

9 - H = AEC-Q101 qualified

10 - Environmental digit:

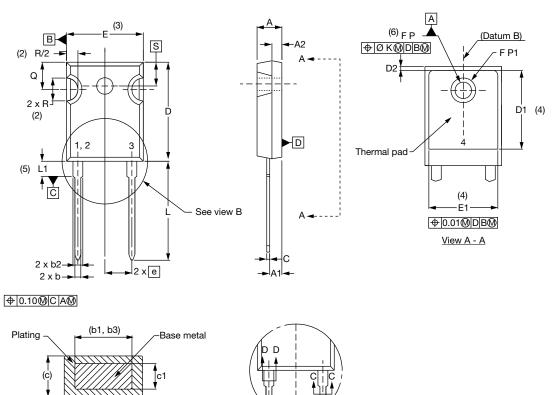
N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5PH6012LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				
SPICE model	www.vishay.com/doc?97086				

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	254	0.0	0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217 BSC		
	•		•	•	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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